

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Wang, Shih-Yuan; Chen, Yong
Assignee: LumiLeds Lighting, U.S., LLC
Title: Growing a Low Defect Gallium Nitride Based Semiconductor (as amended)
Continuation of Serial No.: 09/263,654
Parent Application Filing Date: March 5, 1999
Examiner: Q. Leung
Group Art Unit: 2881
Docket No.: M-10937-1C US

San Jose, California
October 26, 2001

COMMISSIONER FOR PATENTS
Washington, D. C. 20231

PRELIMINARY AMENDMENT

Dear Sir:

Prior to examining this patent application, please enter the following. The amendments are identified in the appendices.

AMENDMENTS

IN THE TITLE

Please amend the title to read as follows:

--Growing a Low Defect Gallium Nitride Based Semiconductor--

IN THE SPECIFICATION

Please insert the following heading and paragraph on page 1 before line 3:

LAW OFFICES OF
SKJERVEN MORRILL
MACPHERSON LLP

25 METRO DRIVE
SUITE 700
SAN JOSE, CA 95110
(408) 453-9200
FAX (408) 453-7979